

# AOS Semiconductor Product Reliability Report

A08807 rev A

**Plastic Encapsulated Device** 

**ALPHA & OMEGA Semiconductor, Inc** 

495 Mercury Drive Sunnyvale, CA 94085 U.S.

Tel: (408) 830-9742 <u>www.aosmd.com</u>



This AOS product reliability report summarizes the qualification result for AO8807. Accelerated environmental tests are performed on a specific sample size, and then followed by electrical test at end point. Review of final electrical test result confirms that AO8807 passes AOS quality and reliability requirements. The released product will be categorized by the process family and be monitored on a quarterly basis for continuously improving the product quality.

### **Table of Contents:**

- Product Description
- II. Package and Die information
- III. Environmental Stress Test Summary and Result
- IV. Reliability Evaluation

#### I. Product Description:

The AO8807 uses advanced trench technology to provide excellent R<sub>DS(ON)</sub>, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch.

- -RoHS Compliant
- -Halogen Free

| Absolute Maximum Ratings T <sub>A</sub> =25°C unless otherwise noted |                      |                                   |            |       |  |  |
|--|----------------------|-----------------------------------|------------|-------|--|--|
| Parameter  |                      | Symbol                            | Maximum    | Units |  |  |
| Drain-Source Voltage   |                      | V <sub>DS</sub>                   | -12        | V     |  |  |
| Gate-Source Voltage  |                      | V <sub>GS</sub>                   | ±8         | V     |  |  |
| Continuous Drain   | T <sub>A</sub> =25°C |                                   | -6.5       |       |  |  |
| Current  | T <sub>A</sub> =70°C | I <sub>D</sub>                    | -5         | A     |  |  |
| Pulsed Drain Current <sup>c</sup>                                    |                      | I <sub>DM</sub>                   | -60        |       |  |  |
|  | T <sub>A</sub> =25°C | D                                 | 1.4        | w     |  |  |
| Power Dissipation <sup>B</sup>                                       | T <sub>A</sub> =70°C | ⊢P <sub>D</sub>                   | 0.9        | vv v  |  |  |
| Junction and Storage Temperature Range                               |                      | T <sub>J</sub> , T <sub>STG</sub> | -55 to 150 | °C    |  |  |

| Thermal Characteristics        |              |                  |     |       |      |  |
|--------------------------------|--------------|------------------|-----|-------|------|--|
| Parameter                      | Symbol       | Тур              | Max | Units |      |  |
| Maximum Junction-to-Ambient A  | t ≤ 10s      | В                | 73  | 90    | °C/W |  |
| Maximum Junction-to-Ambient AD | Steady-State | R <sub>eJA</sub> | 96  | 125   | °C/W |  |
| Maximum Junction-to-Lead       | Steady-State | R <sub>eJL</sub> | 63  | 75    | °C/W |  |



### II. Die / Package Information:

AO8807

Process Standard sub-micron

Low voltage P channel process

Package Type TSSOP-8

**Lead Frame** Cu, D/pad, Ag spot

Die Attach Ag epoxy
Bond wire 2 mils Au wire

Mold Material Epoxy resin with silica filler

Flammability Rating
Backside Metallization
Woisture Level

UL-94 V-0
Ti / Ni / Ag
Up to Level 1 \*

Note \* based on info provided by assembler and mold compound supplier

## III. Result of Reliability Stress for AO8807

| Test Item                        | Test Condition  | Time<br>Point                 | Lot Attribution | Total<br>Sample<br>size | Number of Failures |
|----------------------------------|---|-------------------------------|-----------------|-------------------------|--------------------|
| Solder<br>Reflow<br>Precondition | 168hr 85°c /85RH +3<br>cycle reflow @ 260°c               | -                             | 3 lots          | 495 pcs                 | 0                  |
| HTGB                             | Temp = 150°c ,<br>Vgs=100% of Vgsmax                      | 168hrs<br>500 hrs<br>1000 hrs | 1 lot           | 77 pcs                  | 0                  |
|                                  |   |                               | (Note A*)       | 77 pcs / lot            |                    |
| HTRB                             | Temp = 150°c ,<br>Vds=80% of Vdsmax                       | 168hrs<br>500 hrs<br>1000 hrs | 1 lot           | 77 pcs                  | 0                  |
|                                  |   |                               | (Note A*)       | 77 pcs / lot            |                    |
| HAST                             | 130 +/- 2°c , 85%RH,<br>33.3 psi, Vgs = 80% of<br>Vgs max | 100 hrs                       | 3 lots          | 165 pcs                 | 0                  |
| Pressure Pot                     | 121°c , 29.7psi,  | 96 hrs                        | (Note B**)      | 55 pcs / lot<br>165 pcs | 0                  |
| riessule rot                     | RH=100%   | 30 1113                       | 3 lots          | 100 pcs                 |                    |
|                                  |   |                               | (Note B**)      | 55 pcs / lot            |                    |
| Temperature<br>Cycle             | -65°c to 150°c,<br>air to air,                            | 250 / 500<br>cycles           | 3 lots          | 165 pcs                 | 0                  |
|                                  |   |                               | (Note B**)      | 55 pcs / lot            |                    |



# III. Result of Reliability Stress for AO8807 Continues

| DPA            | Internal Vision<br>Cross-section<br>X-ray | NA                    | 5<br>5<br>5    | 5<br>5<br>5                      | 0 |
|----------------|---|-----------------------|----------------|----------------------------------|---|
| CSAM           |   | NA                    | 5              | 5                                | 0 |
| Bond Integrity | Room Temp<br>150°c bake<br>150°c bake     | 0hr<br>250hr<br>500hr | 40<br>40<br>40 | 40 wires<br>40 wires<br>40 wires | 0 |
| Solderability  | 245°c                                     | 5 sec                 | 15             | 15 leads                         | 0 |

**Note A:** The HTGB and HTRB reliability data presents total of available AO8807 burn-in data up to the published date.

**Note B:** The pressure pot, temperature cycle and HAST reliability data for AO8807 comes from the AOS generic package qualification data.

#### IV. Reliability Evaluation

FIT rate (per billion): 46 MTTF = 2478 years

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size of the selected product (AO8807). Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

**Failure Rate** =  $\text{Chi}^2 \times 10^9 / [2 \text{ (N) (H) (Af)}] = 1.83 \times 10^9 / [2x2x77x500x258] = 46 \text{ MTTF} = <math>10^9 / \text{FIT} = 2.17 \times 10^7 \text{hrs} = 2478 \text{ years}$ 

 $Chi^2$  = Chi Squared Distribution, determined by the number of failures and confidence interval N = Total Number of units from HTRB and HTGB tests

H = Duration of HTRB/HTGB testing

Af = Acceleration Factor from Test to Use Conditions (Ea = 0.7eV and Tuse = 55℃)

Acceleration Factor [Af] = Exp [Ea / k (1/Tj u - 1/Tj s)]

**Acceleration Factor ratio list:** 

|    | 55 deg C | 70 deg C | 85 deg C | 100 deg C | 115 deg C | 130 deg C | 150 deg C |
|----|----------|----------|----------|-----------|-----------|-----------|-----------|
| Af | 258      | 87       | 32       | 13        | 5.64      | 2.59      | 1         |

Tjs = Stressed junction temperature in degree (Kelvin), K = C+273.16

Tju =The use junction temperature in degree (Kelvin), K = C+273.16

**k** = Boltzmann's constant, 8.617164 X 10<sup>-5</sup>eV/K